NSN 5961-01-021-5759

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-021-5759 **Inclosure Material:** Metal **Overall Length:** 1.253 inches **Function For Which Designed:** Rectifier **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.424 inches and 0.437 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 working peak reverse voltage and 24.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 40.00 amperes forward current, average absolute and 500.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud **Specification Data:** 80131-release 6425 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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